

## Silicon Standard Recovery Diode

$V_{RRM} = 400\text{ V} - 600\text{ V}$

$I_F = 35\text{ A}$

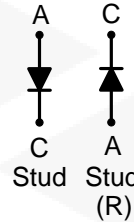
### Features

- High Surge Capability
- Types from 400 to 600 V  $V_{RRM}$
- Not ESD Sensitive

### Note:

1. Standard polarity: Stud is cathode.
2. Reverse polarity (R): Stud is anode.
3. Stud is base.

DO-5 Package



### Maximum ratings, at $T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified ("R" devices have leads reversed)

Parameter	Symbol	Conditions	1N1188 (R)	1N1189 (R)	1N1190 (R)	Unit
Repetitive peak reverse voltage	$V_{RRM}$		400	500	600	V
RMS reverse voltage	$V_{RMS}$		280	350	420	V
DC blocking voltage	$V_{DC}$		400	500	600	V
Continuous forward current	$I_F$	$T_C \leq 140\text{ }^\circ\text{C}$	35	35	35	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25\text{ }^\circ\text{C}$ , $t_p = 8.3\text{ ms}$	595	595	595	A
Operating temperature	$T_j$		-55 to 150	-55 to 150	-55 to 150	$^\circ\text{C}$
Storage temperature	$T_{stg}$		-55 to 150	-55 to 150	-55 to 150	$^\circ\text{C}$

### Electrical characteristics, at $T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	1N1188 (R)	1N1189 (R)	1N1190 (R)	Unit
Diode forward voltage	$V_F$	$I_F = 35\text{ A}$ , $T_j = 25\text{ }^\circ\text{C}$	1.2	1.2	1.2	V
Reverse current	$I_R$	$V_R = 50\text{ V}$ , $T_j = 25\text{ }^\circ\text{C}$	10	10	10	$\mu\text{A}$
		$V_R = 50\text{ V}$ , $T_j = 140\text{ }^\circ\text{C}$	10	10	10	mA

### Thermal characteristics

Parameter	Symbol	Conditions	1N1188 (R)	1N1189 (R)	1N1190 (R)	Unit
Thermal resistance, junction - case	$R_{thJC}$		0.25	0.25	0.25	$^\circ\text{C/W}$

Figure .1-Typical Forward Characteristics

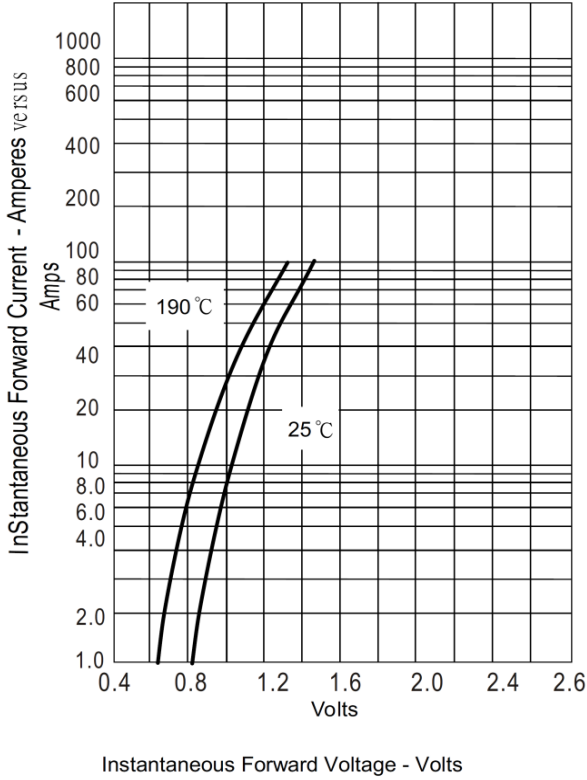


Figure .2-Forward Derating Curve

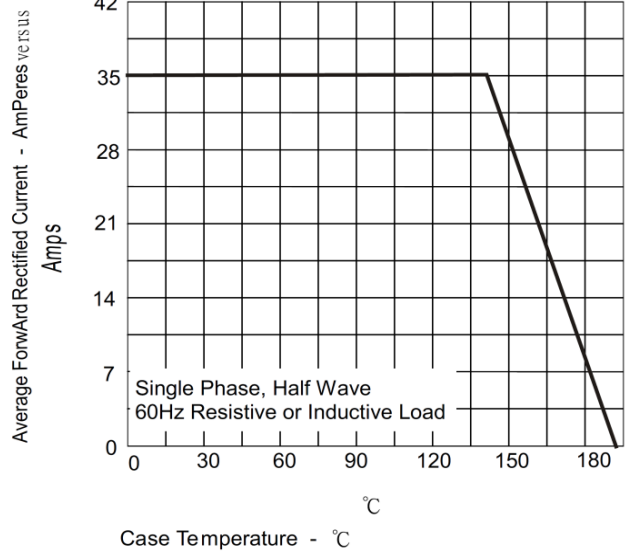


Figure .4-Typical Reverse Characteristics

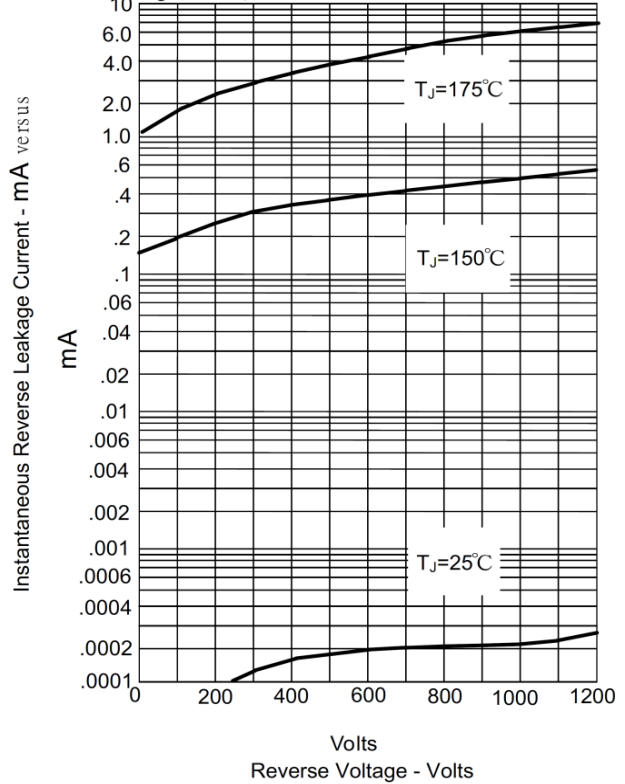
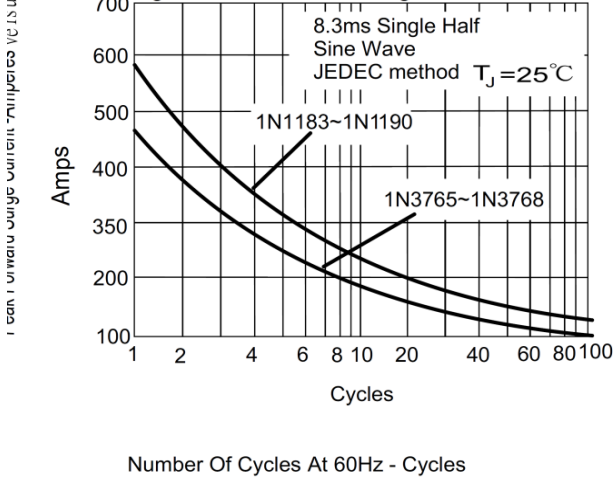
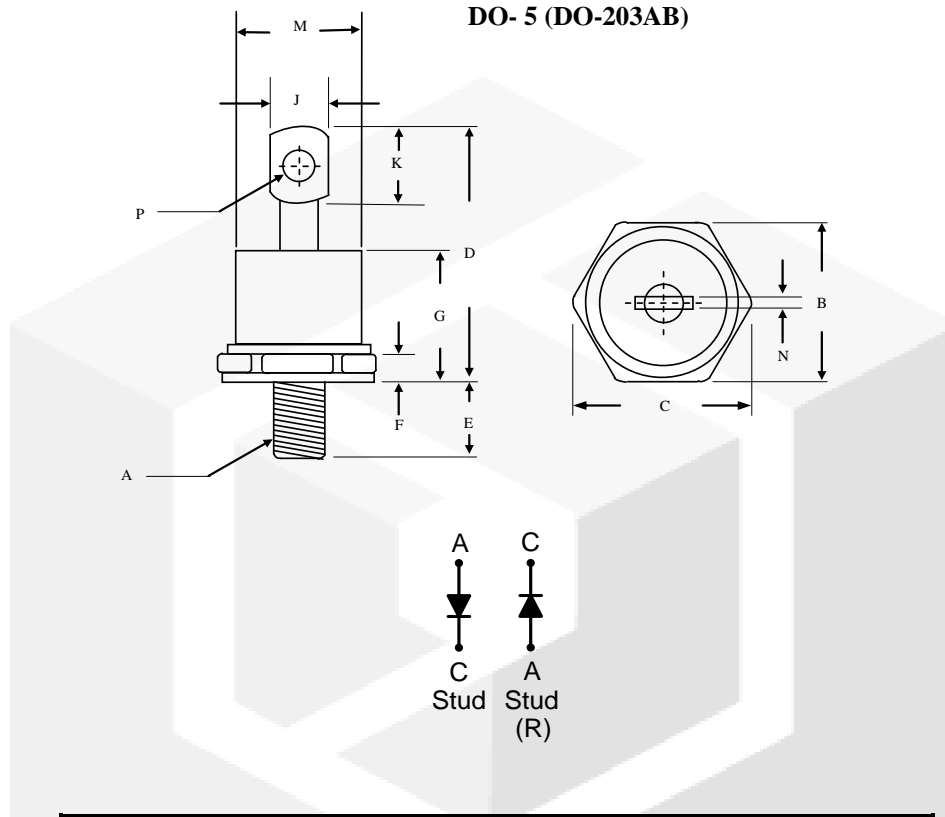


Figure .3-Peak Forward Surge Current



**Package dimensions and terminal configuration**

Product is marked with part number and terminal configuration.



	Inches		Millimeters	
	Min	Max	Min	Max
A	1/4 -28 UNF			
B	0.669	0.687	17.19	17.44
C	-----	0.794	-----	20.16
D	-----	1.020	-----	25.91
E	0.422	0.453	10.72	11.50
F	0.115	0.200	2.93	5.08
G	-----	0.460	-----	11.68
J	-----	0.280	-----	7.00
K	0.236	-----	6.00	-----
M	-----	0.589	-----	14.96
N	-----	0.063	-----	1.60
P	0.140	0.175	3.56	4.45

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